TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCV373FT, TC74VHCV373FK

Octal Schmitt D-Type Latch with 3-State Output

The TC74VHCV373 is an advanced high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate CMOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

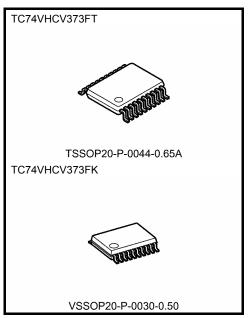
This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}).

When the \overline{OE} input is high, the eight outputs are in a high impedance state.

Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the TC74VHCV373 are capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

Input protection and output circuit ensure that 0 to 5.5~V can be applied to the input and output $^{(Note)}$ pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state



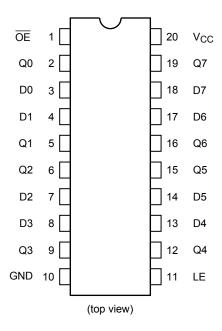
Weight

TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Features

- High speed: $t_{pd} = 5.4 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 2 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- Wide operating voltage range: $V_{CC (opr)} = 1.8 \text{ V}$ to 5.5 V
- Ouput current: $|I_{OH}|/I_{OL} = 16 \text{ mA (min)} (V_{CC} = 4.5 \text{ V})$
- Available in TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 373 typ

Pin Assignment



Truth Table

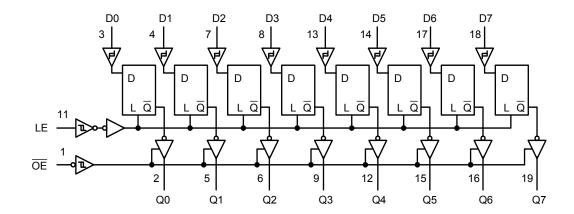
	Inputs	Output			
ŌĒ	LE	D	Output		
Н	Х	Х	Z		
L	L	Х	Qn		
L	Н	L	L		
L	Н	Н	Н		

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram





Absolute Maximum Ratings (Note1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	−0.5 to 7.0	V
DC output voltage	Vour	-0.5 to 7.0 (Note 2)	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	I _{IK}	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	P _D	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Operating Ranges (Note1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	1.8 to 5.5	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output valtage	V	0 to 5.5 (Note 2)	V	
Output voltage	V _{OUT}	0 to V _{CC} (Note 3)	V	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 20 (V _{CC} = 3.3 ± 0.3 V)	ms/V	
input rise and fair time	avav	0 to 1 (V_{CC} = 5 ± 0.5 V)	1115/ V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V_{CC} or GND.

Note 2: Output in off-state

Note 3: High or low state.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol Test Condition			Ta = 25°C		Ta = −40 to 85°C		Unit		
			V _{CC} (V)	Min	Тур.	Max	Min	Max		
Positive threshold voltage	V _P		_		_ _ _	_ _ _	1.65 1.85 2.20	_ _ _	1.65 1.85 2.20	
				4.5 5.5		_	3.15 3.85	_	3.15 3.85	
	.,			1.8 2.3	0.15 0.45	_ _	_ _	0.15 0.45	_ _	V
Negative threshold voltage	V _N	_		3.0 4.5 5.5	0.90 1.35 1.65	_ _ _	_ _ _	0.90 1.35 1.65	_ _ _	
Hysteresis voltage	V _H	_		1.8 2.3 3.0 4.5 5.5	0.15 0.20 0.30 0.40 0.50	_ _ _ _	1.05 1.10 1.20 1.40 1.60	0.15 0.20 0.30 0.40 0.50	1.05 1.10 1.20 1.40 1.60	٧
High-level output voltage		V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8 3.0 4.5	1.7 2.9 4.4	1.8 3.0 4.5	_ _ _ _	1.7 2.9 4.4	_ _ _ _	V
			$I_{OH} = -8 \text{ mA}$ $I_{OH} = -16 \text{ mA}$	3.0 4.5	2.58 3.94	_	_	2.48 3.80	_	
Low-level output voltage	V _{OL} V _{IN} = V _{IH} or		I _{OL} = 50 μA	1.8 3.0 4.5	_ _ _	0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	V
g-		= V _{IH} or V _{IL}	I _{OL} = 8 mA I _{OL} = 16 mA	3.0 4.5		_	0.36 0.44		0.44 0.55	
3-state output off-state current	l _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5V		1.8 to 5.5	_	_	±0.5	_	±5.0	μA
Power-off leakage current	l _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	-	_	0.5	_	5.0	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	V _{IN} = V _{CC} or	GND	5.5	_	_	2.0	_	20.0	μA



Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	est Condition		Ta = 25°C		Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width			2.5 ± 0.2	_	6.0	6.5	
(LE)	t _{w (H)}	_	3.3 ± 0.3	_	5.0	5.0	ns
			5.0 ± 0.5	-	5.0	5.0	
			2.5 ± 0.2	_	4.5	5.0	
Minimum set-up time	t _S	_	3.3 ± 0.3	_	4.0	4.0	ns
			5.0 ± 0.5	-	4.0	4.0	
Minimum hold time			2.5 ± 0.2	_	1.5	1.5	
	t _h	_	3.3 ± 0.3	_	1.0	1.0	ns
			5.0 ± 0.5	_	1.0	1.0	

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AC Electrical Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Tes	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	- ,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			05.00	15	_	10.7	15.7	1.0	19.0	-
			2.5 ± 0.2	50	_	13.5	19.3	1.0	22.0	
Propagation delay time	t_{pLH}		22.02	15	_	7.4	11.0	1.0	13.0	
(LE-Q)	t_{pHL}	_	3.3 ± 0.3	50	_	9.5	14.5	1.0	16.5	ns
,			50.05	15	_	5.4	7.2	1.0	8.5	
			5.0 ± 0.5	50	_	7.1	9.2	1.0	10.5	
			25.02	15	_	13.0	17.7	1.0	20.1	
			2.5 ± 0.2	50	-	15.5	21.1	1.0	24.1	
Propagation delay time	t_{pLH}		3.3 ± 0.3	15	_	8.8	12.9	1.0	14.8	no
(D-Q)	t_{pHL}	_	3.3 ± 0.3	50	_	10.8	15.5	1.0	17.7	- ns
			5.0 ± 0.5	15	_	6.2	7.2	1.0	8.5	
				50	1	8.0	9.3	1.0	10.6	
	^t pZL ^t pZH	R _L = 1 kΩ	2.5 ± 0.2	15	_	9.4	15.8	1.0	19.0	ns
				50	_	12.3	18.8	1.0	22.0	
3-state output enable			Ω 3.3 ± 0.3 0.3 ± 0.5	15	_	6.5	11.4	1.0	13.5	
time				50	_	8.7	14.9	1.0	17.0	
				15	_	4.5	8.1	1.0	9.5	
				50	_	6.2	10.1	1.0	11.5	
	t_pLZ		2.5 ± 0.2	50	_	14.5	17.4	1.0	19.0	
3-state output disable time	t _{pHZ}	$R_L = 1 k\Omega$	3.3 ± 0.3	50	_	10.9	13.2	1.0	15.0	ns
	-priz		5.0 ± 0.5	50	_	8.0	9.2	1.0	10.5	
	t _{osLH}		2.5 ± 0.2	50	_	_	1.5	_	1.5	
Output to output skew	tosHL	(Note 1)	3.3 ± 0.3	50	_	_	1.5	_	1.5	ns
	-05ITL		5.0 ± 0.5	50	_	_	1.0	_	1.0	
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Output capacitance	C _{OUT}		_		_	6	_	_	_	pF
Power dissipation capacitance	C_{PD}			(Note 2)	_	21	_	_	_	pF

Note 1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per latch)

And the total CPD when n pcs. of Latch operate can be gained by the following equation:

C_{PD} (total) = 11 + 10·n

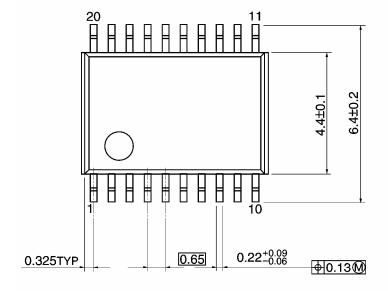


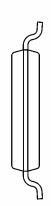
Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

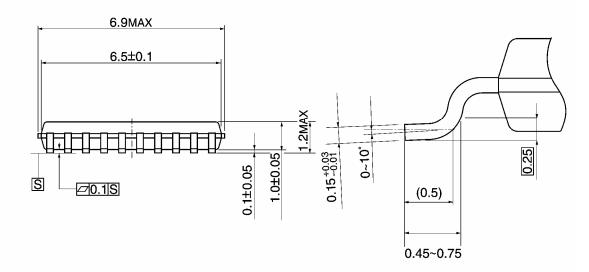
Characteristics	Cumbal	Test Condition		Ta = 25°C		Unit
Characteristics	Symbol		V _{CC} (V)	Тур.	Max	Offic
Quiet output maximum dynamic	V	C. = 50 pE	3.3	0.3	_	V
V _{OL}	V_{OLP}	C _L = 50 pF	5.0	0.7	-	V
Quiet output minimum dynamic	V	C _I = 50 pF	3.3	-0.1	_	V
V _{OL}	V_{OLV}	С_ = 50 рг	5.0	-0.4	_	V
Minimum high level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0	-	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0		1.5	V

Package Dimensions

TSSOP20-P-0044-0.65A Unit: mm



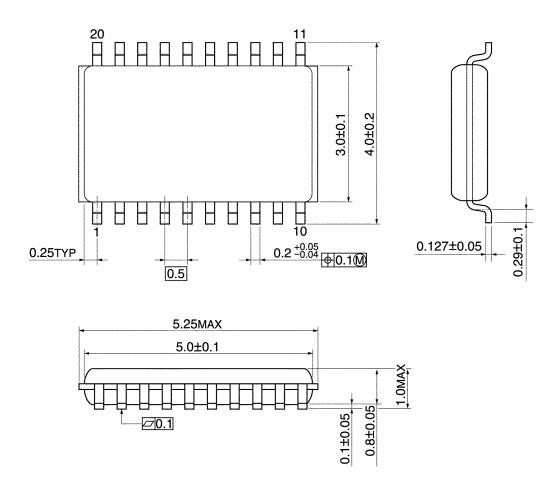




Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

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